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Powered-off Protection, High Speed, 1.65 V to 5.5 V, SPDT Analog Switch (2:1 Multiplexer / Demultiplexer Bus Switch)

DESCRIPTION

The DG3157E is a high speed single-pole double-throw analog switch designed for +1.65 V to +5.5 V single power rail operation.

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Fabricated with high density CMOS technology, the DG3157E achieves low on-resistance, fast switching speed, and high bandwidth while maintains low power consumption.

The DG3157E can handle both analog and digital signals and permits signals with amplitudes of up to V+ to be transmitted in either direction.

When the select pin is low, B₀ is connected to the output A pin. When the select pin is high, B1 is connected to the output A pin. The path that is open will have a high impedance state with respect to the output. Break before make switching performance is guaranteed.

A powered-off protection circuit is built into the switch to prevent an abnormal current flow from COM pin to V+ during the power-down condition. Each output pin can withstand greater than 7 kV (human body model).

Operation temperature is specified from -40 °C to +85 °C. The DG3157E is available in the compact SC-70-6L package.

FEATURES

- Direct standard cross to industry SN74LVC1G3157, NC7SB3157, NLASB3157, PI5A3157, and STG3157
- Low switch on-resistance (6 Ω)
- +1.65 V to +5.5 V single supply operation
- Powered-off protection
- Control logic inputs can go over V+ up to 5.5 V
- · Low parasitic capacitance, 7 pF at switch off
- · Break before make switching
- Latch-up performance exceeds 200 mA per JESD 78
- High ESD rating
 - 7000 V human body model (JS-001)
 - 1000 V charge device model (JS-002)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- Battery powered devices
- Consumer and computing
- Instrumentation
- Medical equipment

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V-

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· Control and automation

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE					
LOGIC INPUT (S)	FUNCTION				
0	B ₀ connected to A				
1	B ₁ connected to A				

ORDERING INFORMATION						
TEMP. RANGE	PACKAGE	PART NUMBER				
-40 °C to +85 °C	SC-70-6	DG3157EDL-T1-GE3 (halogen-free)				





DG3157E



RoHS

COMPLIANT

HALOGEN

FREE

SC-70 6-Pin



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ABSOLUTE MAXIMUM RATINGS						
PARAMETER		LIMIT	UNIT			
V+, A, B ₀ , B ₁ , S reference to GND		-0.3 to 6	V			
Continuous current (any terminal)		± 50	mA			
Peak current (pulsed at 1 ms, 10 %	duty cycle)	± 200	IIIA			
Storage temperature	D suffix	-65 to +150	°C			
Power dissipation (packages) ^a	6-pin SC-70 ^b	250	mW			
ESD / HBM	JS-001	7000	V			
ESD / CDM	JS-002	1000	v			
Latch up	Per JESD78 with 1.5 x V _{abs} max. clamp	200	mA			

Notes

a. All leads welded or soldered to PC board b. Derate 3.1 mW/°C above 70 $^\circ\text{C}$

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

SPECIFICATIONS								
PARAMETER	SYMBOL	UNLESS OT	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED		LIMITS -40 °C to +85 °C			UNIT
	STMBOL	V_S = 0.25 V+ or 0.75 V+, V+ = 1.65 V to 1.95 V $^{\rm e}$ V_S = 0.2 V+ or 0.65 V+, V+ = 2.3 V to 5.5 V $^{\rm e}$		TEMP. ^a	MIN. ^b	TYP. °	MAX. ^b	UNIT
DC Characteristics	•							
High level input voltage	N	V+ = -	V+ = 1.65 V to 1.95 V		0.75 V+	-	-	
r light level liput voltage	V _{SH}	V+ =	2.3 V to 5.5 V	Full	0.65 V+	-	-	v
Low level input voltage	V _{SL}		1.65 V to 1.95 V	Full	-	-	0.25 V+	v
Low level input voltage	VSL	V+ =	2.3 V to 5.5 V	Full	-	-	0.2 V+	
			$V_{BN} = 0 V, I_A = 30 mA$	Full	-	8	11	
		V+ = 4.5 V	$V_{BN} = 2.3 \text{ V}, I_A = -30 \text{ mA}$	Full	-	6	9	
			$V_{BN} = 4.5 \text{ V}, I_A = -30 \text{ mA}$	Full	-	7	9	
		V+ = 3 V	$V_{BN} = 0 V, I_A = 24 mA$	Full	-	10	14	
On resistance	R _{ON}	V+ = 0 V	$V_{BN} = 3 V, I_A = -24 mA$	Full	-	9	12	
		V+ = 2.3 V	$V_{BN} = 0 V, I_A = 8 mA$	Full	-	13	18	
		V+=2.3 V	$V_{BN} = 2.3 \text{ V}, I_A = -8 \text{ mA}$	Full	-	12	16	
		V+ = 1.65 V	$V_{BN} = 0 V$, $I_A = 4 mA$	Full	-	20	26	
			$V_{BN} = 1.65 \text{ V}, \text{ I}_{A} = -4 \text{ mA}$	Full	-	18	23	Ω
		R_{FLAT} 0 < V_{BN} < V+	$V+ = 4.5 V$, $I_A = -30 mA$	Room	-	2	-	
On resistance flatness	Brut		V+ = 3 V, I _A = -24 mA	Room	-	4	-	
On resistance flatness R _{FLAT}	TFLAI		$V+ = 2.3 V, I_A = -8 mA$	Room	-	10	-	
				$V+ = 1.65 V$, $I_A = -4 mA$	Room	-	58	-
	ΔR_{ON}		_{BN} = 3.15 V, I _A = -30 mA	Room	-	0.09	-	
On resistance matching		V+ = 3 V, V _B	_N = 2.1 V, I _A = -24 mA	Room	-	0.13	-	
between channels		V+ = 2.3 V, V _{BN} = 1.6 V, I _A = -8 mA		Room	-	0.15	-]
		V+ = 1.65 V, V	/ _{BN} = 1.15 V, I _A = -4 mA	Room	-	0.16	-	
nput leakage current		V. – F	5.5 V, V _S = 5.5 V	Room	-0.1	-	0.1	
input leakage curreill	ا _S	v + = c	$3.5 \text{ v}, \text{ v}_{\text{S}} = 5.5 \text{ v}$	Full	-1	-	1	
Off stage switch leakage		V+ = 5.5 V, V _A = 1 V / 4.5 V, V _B = 4.5 V / 1 V		Room	-0.1	-	0.1	
on stage switch leakage	I _{BN(off)}			Full	-1	-	1	
On state switch leakage	I _{BN(on)}	V+ = 5.5 V, $V_A = V_B = 1$ V or 4.5 V		Room	-0.1	-	0.1	μA
On state Switch leakage				Full	-1	-	1]
Power down leakage	laa	$V_{+} = 0 V, V_{A} = 5 V, B_{0}, B_{1} \text{ open}, V_{S} = GND$ $V_{+} = 0 V, V_{B0}, V_{B1} = 5 V, A \text{ open}, V_{S} = GND$		Full	-	-	5	
i uvei uuwii leakaye	I _{PD}			Full	-	-	5	
Power Supply	1			I				
Power supply range	V+			Full	1.65	-	5.5	V
Quiescent supply current	I+	V+ = 5.5	$V_{+} = 5.5 V, V_{S} = V_{+} \text{ or GND}$		-	-	1	μA
	1+	$v_{\rm T} = 0.5 v, v_{\rm S} = v_{\rm T} \text{ or give}$		Full	-	-	5	μΛ

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DG3157E

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SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED		TEMP. ^a	-40	C to +8		UNIT
	OTMOOL	$V_{\rm S} = 0.25 \text{ V} + \text{ or } 0.7$ $V_{\rm S} = 0.2 \text{ V} + \text{ or } 0.6$	5 V+, V+ = 1.65 V to 1.95 V ^e 55 V+, V+ = 2.3 V to 5.5 V ^e		MIN. ^b	۲YP. ۵	MAX. ^b	UNIT
AC Electrical Characterist	tics ^e							
			V+ = 1.65 V to 1.95 V	Full	-	4	-	
Prop delay time ^f	t _{PHL} /t _{PLH}	$V_A = 0 V,$	V+ = 2.3 V to 2.7 V	Full	-	3	-	
Frop delay lime	'PHL/ 'PLH	see Fig. 3	V+ = 3 V to 3.6 V	Full	-	2	-	
			V+ = 4.5 V to 5.5 V	Full	-	2	-	
			V+ = 1.65 V to 1.95 V	Room	-	32	-	
			v+ = 1.05 v to 1.95 v	Full	-	34	-	
		$V_{LOAD} = 2 \times V +$	V+ = 2.3 V to 2.7 V	Room	-	22	-	
Output anable time f	± /±	for t _{PZL} ,	V + = 2.3 V 10 2.7 V	Full	-	23	-	
Output enable time ^f	t _{PZL} /t _{PZH}	$V_{LOAD} = 0 V$ for t _{PZH} ,		Room	-	19	-	1
		see Fig. 4	V+ = 3 V to 3.6 V	Full	-	20	-	1
				Room	-	16	-	
			V+ = 4.5 V to 5.5 V	Full	-	16	-	
				Room	-	22	-	ns
			V+ = 1.65 V to 1.95 V	Full	-	23	-	- - -
		$V_{LOAD} = 2 \times V +$		Room	-	18	-	
Output disable time ^f	t _{PLZ} /t _{PHZ}	for t _{PLZ} , V _{LOAD} = 0 V for t _{PHZ} , see Fig. 4	V+ = 2.3 V to 2.7 V	Full	-	19	-	
			V+ = 3 V to 3.6 V	Room	-	16	-	
				Full	-	16	-	
				Room	-	13	-	
			V+ = 4.5 V to 5.5 V	Full	-	14	-	
		V+ = 7	1.65 V to 1.95 V	Full	0.5	-	-	
		V+ =	2.3 V to 2.7 V	Full	0.5	-	-	
Break-before-make time d	t _{BBM}	V+ =	3 V to 3.65 V	Full	0.5	-	-	
		V+ = 4.5 V to 5.5 V		Full	0.5	-	-	
		$\begin{array}{c} C_L = 0.1 \text{ nF}, \\ V_{GEN} = 0 \text{ V} \\ R_{GEN} = 0 \ \Omega \end{array}$	V+ = 5 V	Room	-	1.3	-	
Charge injection ^d Q	Q		V+ = 3.3 V	Room	-	0.5	-	рС
Analog Switch Characteris	stics							
Off isolation ^d	OIRR	R 5	0 Ω, f = 10 MHz	Room	-	-61	-	dB
Crosstalk ^d	X _{TALK}	n_ = 5		Room	-	-61	-	UD
-3 dB bandwidth ^d	BW	$R_L = 50 \ \Omega$		Room	-	580	-	MHz
Capacitance								
Control pin capacitance d	CIN		V+ = 0 V	Room	-	6	-	
B port off capacitance d	C _{IO-B}			Room	-	7	-	pF
A port capacitance when switch enable ^d	C _{IO-A(on)}	V+ = 5 V		Room	-	12	-	1

Notes

a. Room = 25 °C, full = as determined by the operating suffix

b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet

c. Typical values are for design aid only, not guaranteed nor subject to production testing

d. Guarantee by design, nor subjected to production test

e. V_S = input voltage to perform proper function

f. Guaranteed by design and not production tested. The bus switch propagation delay is a function of the RC time constant contributed by the on-resistance and the specified load capacitance with an ideal voltage source (zero output impedance) driving the switch

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DG3157E

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LOGIC DIAGRAM POSITIVE LOGIC



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)







Power Down Leakage Current vs. Temperature



Power Down Leakage Current vs. V_A

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AC LOADING AND WAVEFORMS







Notes

- C_L includes probe and jig capacitance
- Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control
- Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_0 = 50 Ω
- · The outputs are measured one at a time with one transition per measurement
- t_{PLZ} and t_{PHZ} are the same as t_{dis}
- t_{PZL} and t_{PZH} are the same as t_{dis}
- t_{PLH} and t_{PHL} are the same as t_{dis}
- V_{LD} = 2 V+

V+ V+ V+

 $B_{1} \circ B_{1} \circ A$ $B_{0} \circ B_{0} \circ$

 C_{L} (includes fixture and stray capacitance)

Fig. 5 - Break-Before-Make Interval



 $\label{eq:Q} Q = \ \Delta V_{OUT} \ x \ C_L$ IN depends on switch configuration: input polarity determined by sense of switch.

Off

On

ΔV_{OUT}





Fig. 7 - Off-Isolation





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V۸

 V_S

On







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